



5/13/2009

**PRODUCT RELIABILITY REPORT
FOR**

DS8313, Rev A2

Maxim Integrated Products

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Prepared by:

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Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Maxim products:

DS8313, Rev A2

In addition, Maxim's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at <http://www.maxim-ic.com/TechSupport/dsreliability.html>.

Device Description:

A description of this device can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l_datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

$$AfT = \exp((Ea/k) * (1/Tu - 1/Ts)) = tu/ts$$

AfT = Acceleration factor due to Temperature
tu = Time at use temperature (e.g. 55°C)
ts = Time at stress temperature (e.g. 125°C)
k = Boltzmann's Constant (8.617 x 10⁻⁵ eV/°K)
Tu = Temperature at Use (°K)
Ts = Temperature at Stress (°K)
Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

$$AfV = \exp(B * (Vs - Vu))$$

AfV = Acceleration factor due to Voltage
Vs = Stress Voltage (e.g. 7.0 volts)
Vu = Maximum Operating Voltage (e.g. 5.5 volts)
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

$$Fr = X / (ts * AfV * AfT * N * 2)$$

X = Chi-Sq statistical upper limit
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

$$MTTF = 1/Fr$$

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

FAILURE RATE:	MTTF (YRS):	68697	FITS:	1.7
	DEVICE HOURS:	584640	FAILS:	0

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

Cf: 60% **Ea: 0.7** **B: 0** **Tu: 25 °C** **Vu: 6 Volts**

The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. **Bold** Product Number denotes specific product data.

Device Information:

Process: B8, San Antonio B8 flow with TMA Topglass.
 Passivation: OxyNit LaserNoA&E - Pass/Nov.TEOS/OxyNit -Gen.LaserP
 Die Size: 84 x 70
 Number of Transistors: 7299
 Interconnect: Aluminum / 0.5% Copper
 Gate Oxide Thickness: NA

ESD HBM ALL PINS

DESCRIPTION	DATE CODE/PRODUCT/LOT	CONDITION	READPOINT	QTY	FAILS	FA#
ESD SENSITIVITY	0851 DS8313 QM941961	JESD22-A114 HBM 500 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0851 DS8313 QM941961	JESD22-A114 HBM 1000 VOLTS	1 PUL'S	3	0	
Total:					0	

ESD HBM CARD INTERFACE PINS

DESCRIPTION	DATE CODE/PRODUCT/LOT	CONDITION	READPOINT	QTY	FAILS	FA#
ESD SENSITIVITY	0851 DS8313 QM941961	JESD22-A114 HBM 500 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0851 DS8313 QM941961	JESD22-A114 HBM 1000 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0851 DS8313 QM941961	JESD22-A114 HBM 2000 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0851 DS8313 QM941961	JESD22-A114 HBM 4000 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0851 DS8313 QM941961	JESD22-A114 HBM 8000 VOLTS	1 PUL'S	3	0	
Total:					0	

LATCH-UP

DESCRIPTION	DATE CODE/PRODUCT/LOT	CONDITION	READPOINT	QTY	FAILS	FA#
LATCH-UP	0851 DS8313 QM941961	JESD78A, I-TEST 125C		6	0	
LATCH-UP	0851 DS8313 QM941961	JESD78, V-SUPPLY TEST 125C		6	0	
Total:					0	

OPERATING LIFE

DESCRIPTION	DATE	CODE/PRODUCT/LOT	CONDITION	READPOINT	QTY	FAILS	FA#
HIGH TEMP OP LIFE	0724	DS8007	QN616349	125C, 6.0 VOLTS	1000 HRS	45	0
HIGH TEMP OP LIFE	0740	DS8007	QN824614	125C, 6.0 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0740	DS8007	XN716349C	125C, 6.0 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0744	DS8113	QK732036	125C, 6.0 VOLTS	1000 HRS	45	0
HIGH TEMP OP LIFE	0750	DS8007	QN824614	125C, 6.0 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0833	DS8024	QM832036	125C, 6.0 VOLTS	192 HRS	45	0
HIGH TEMP OP LIFE	0834	DS8023	QM840693	125C, 6.0 VOLTS	1000 HRS	45	0
HIGH TEMP OP LIFE	0837	DS2413	WJ942402	125C, 5.25 VOLTS	1000 HRS	45	0
HIGH TEMP OP LIFE	0839	DS8007	SN839727A	125C, 6.0 VOLTS	192 HRS	120	0
HIGH TEMP OP LIFE	0851	DS8313	QM941961	125C, 6.0 VOLTS	1000 HRS	45	0

Total: 0

FAILURE RATE: **MTTF (YRS):** **68697** **FITS:** **1.7**
 DEVICE HOURS: **584640** **FAILS:** **0**